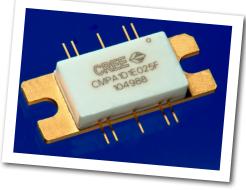
PRELIMINARY



CMPA1D1E025F 25 W, 13.75 - 14.5 GHz, 40 V, Ku-Band GaN MMIC, Power Amplifier

Cree's CMPA1D1E025F is a gallium nitride (GaN) High Electron Mobility Transistor (HEMT) based monolithic microwave integrated circuit (MMIC) on a silicon carbide substrate, using a 0.25 μ m gate length fabrication process. The Ku Band 25W MMIC is targeted for commercial Ku Band applications. It offers high gain and superior efficiency while meets OQPSK linearity required for Satcom applications at 3dB backed off Psat operations. This Ku Band MMIC is available in a 10 lead, 25 mm x 9.9 mm metal/ceramic flanged package.



Typical Performance Over 13.75-14.5 GHz $(T_c = 25^{\circ}C)$

Devenuetor					Unite
Parameter	13.75 GHz	14.0 GHZ	14.25 GHZ	14.5 GHZ	Units
Small Signal Gain	26	27	27	26	dB
Linear Output Power	19	19	20	18	W
Power Gain	19.5	18.6	17.1	16.7	dB
Power Added Efficiency	18	18	17	16	%

Note¹: Measured at -30 dBc, 1.6 MHz from carrier, in the CMPA1D1E025F-TB under OQPSK modulation, 1.6 Msps, PN23, Alpha Filter = 0.2.

Features

- 26 dB Small Signal Gain
- 40 W Typical Pulsed P_{SAT}
- Operation up to 40 V
- P_{AVE} = 42 dBm, linear power under OQPSK
- Class A/B high gain, high efficiency 50 ohm
 MMIC Ku Band high power amplifier

Applications



Satellite Communications Uplink



Absolute Maximum Ratings (not simultaneous)

Parameter	Symbol	Rating	Units	Conditions
Drain-source Voltage	V _{DSS}	84	V _{DC}	25°C
Gate-source Voltage	V _{GS}	-10, +2	V _{DC}	25°C
Power Dissipation	P _{DISS}	94	W	
Storage Temperature	T _{stg}	-55, +150	°C	
Operating Junction Temperature	Т,	225	°C	
Maximum Forward Gate Current	I _{gmax}	10	mA	25°C
Soldering Temperature ¹	Τ _s	245	°C	
Screw Torque	τ	40	in-oz	
Thermal Resistance, Junction to Case	R _{ejc}	1.5	°C/W	P _{DISS} = 94 W, 85°C
Case Operating Temperature	T _c	-40, +85	°C	CW, $P_{\text{DISS}} = 94 \text{ W}$

Note:

¹ Refer to the Application Note on soldering at <u>www.cree.com/products/wireless_appnotes.asp</u>

Electrical Characteristics (Frequency = 13.75 GHz to 14.5 GHz unless otherwise stated; $T_c = 25^{\circ}C$)

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
DC Characteristics ¹						
Gate Threshold	$V_{\rm GS(TH)}$	-3.8	-3.0	-2.3	V	$V_{_{\rm DS}}$ = 10 V, $I_{_{\rm D}}$ = 18.2 mA
Gate Quiscent Voltage	V _Q	-	-2.7	-	V	$V_{_{\rm DS}}$ = 40 V, $I_{_{\rm D}}$ = 240 mA
Saturated Drain Current ²	$I_{\rm DS}$	14.6	16.4	-	А	$V_{_{DS}}$ = 6.0 V, $V_{_{GS}}$ = 2.0 V
Drain-Source Breakdown Voltage	$V_{_{BD}}$	84	100	-	V	$V_{\rm _{GS}}$ = -8 V, $I_{\rm _{D}}$ = 18.2 mA
RF Characteristics ³						
Small Signal Gain	S21	-	26	-	dB	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, $P_{_{IN}}$ = -20 dBm
Input Return Loss	S11	-	-8	-	dB	$V_{_{\rm DD}}$ = 40 V, $I_{_{\rm DQ}}$ = 240 mA, $P_{_{\rm IN}}$ = -20 dBm
Output Return Loss	S22	-	-10	-	dB	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, $P_{_{IN}}$ = -20 dBm
Output Mismatch Stress	VSWR	-	-	5:1	Ψ	No damage at all phase angles, V_{_{DD}} = 40 V, $I_{_{DQ}}$ = 240 mA, P_{_{OUT}} = 41 dBm OQPSK

Notes:

¹ Measured on-wafer prior to packaging.

² Scaled from PCM data.

³ Measured in the CMPA1D1E025F-TB.

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Electrical Characteristics Continued... ($T_c = 25^{\circ}C$)

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
RF Characteristics ^{1,2,3,4}						
Power Added Efficiency	PAE1	-	16.0	-	%	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, Frequency = 13.75 GHz
Power Added Efficiency	PAE2	-	14.0	-	%	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, Frequency = 14.5 GHz
Power Gain	G _{P1}	-	21.5	-	dB	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, Frequency = 13.75 GHz
Power Gain	G _{P2}	-	19.0	-	dB	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, Frequency = 14.5 GHz
OQPSK Linearity	ACLR1	-	-38	-	dBc	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, Frequency = 13.75 GHz
OQPSK Linearity	ACLR2	-	-37	-	dBc	$V_{_{DD}}$ = 40 V, $I_{_{DQ}}$ = 240 mA, Frequency = 14.5 GHz

Notes:

¹ Measured in the CMPA1D1E025F-TB.

² Under OQPSK modulated signal, 1.6 Msps, PN23, Alpha Filter = 0.2.

³ Measured at $P_{AVE} = 41 \text{ dBm}$.

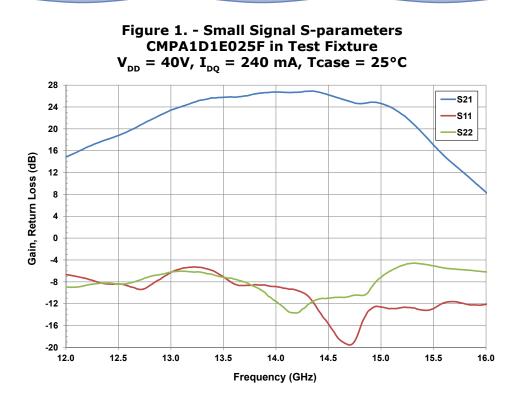
⁴ Fixture loss de-embedded.

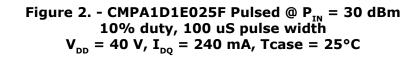
Electrostatic Discharge (ESD) Classifications

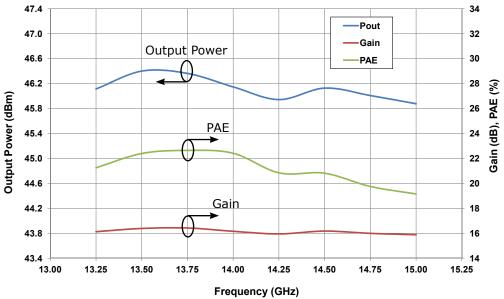
Parameter	Symbol	Class	Test Methodology
Human Body Model	НВМ	1A (> 250 V)	JEDEC JESD22 A114-D
Charge Device Model	CDM	II (200 < 500 V)	JEDEC JESD22 C101-C

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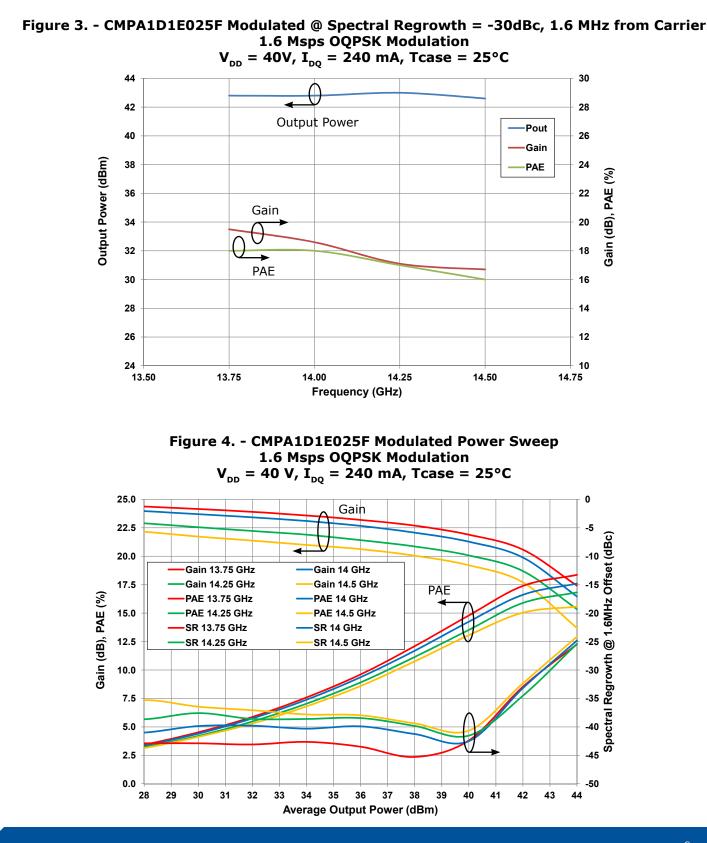




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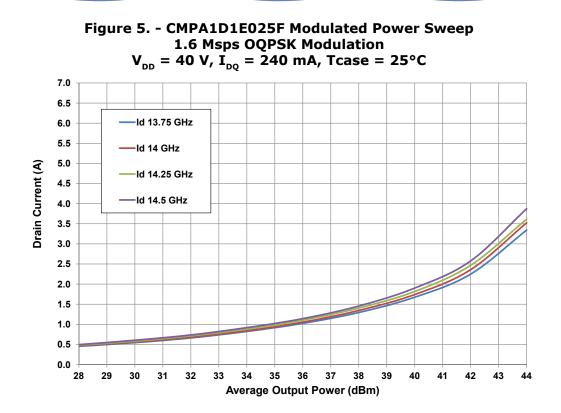




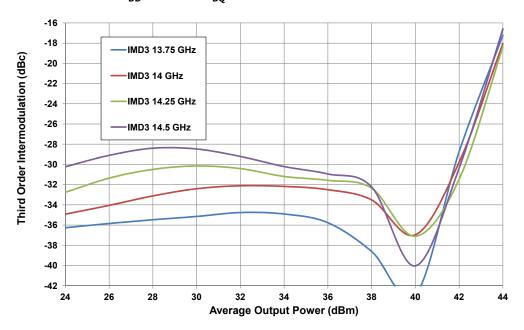
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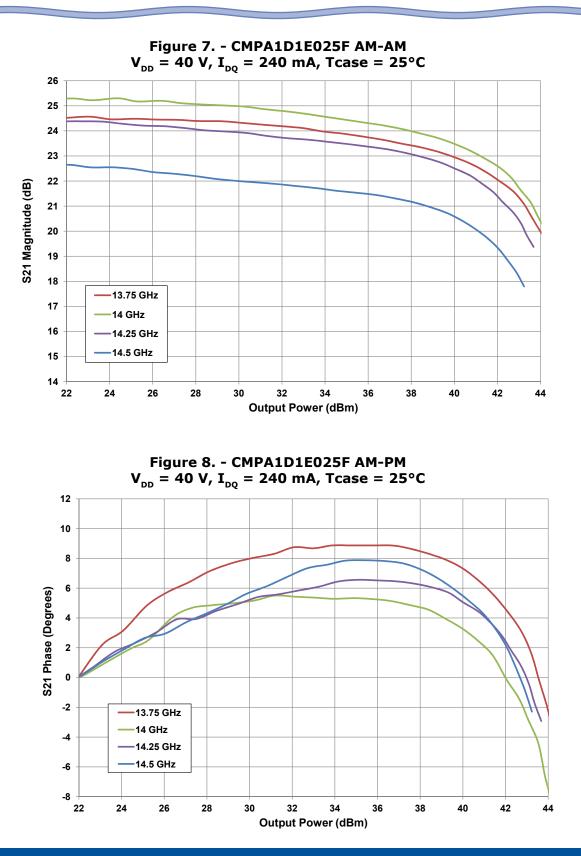




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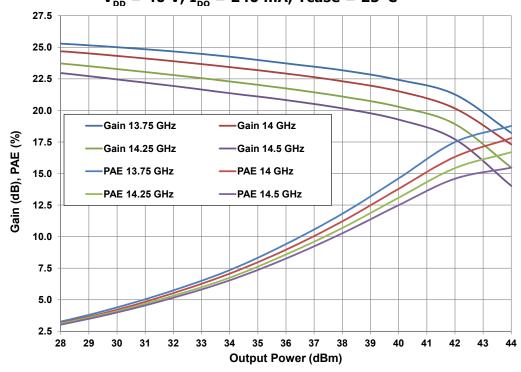
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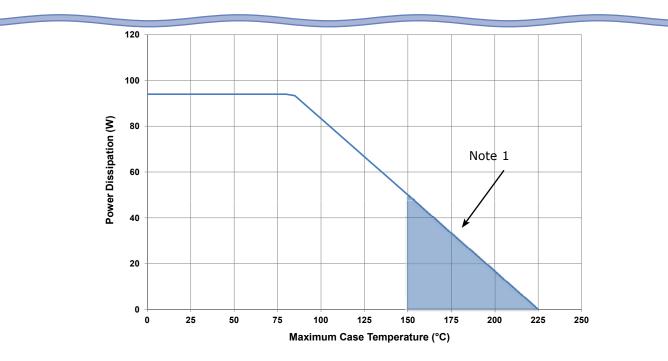
CMPA1D1E025F Rev 0, Preliminary



Figure 9. - CMPA1D1E025F Gain and Power Added Efficiency vs CW Output Power $V_{pp} = 40 V$, $I_{po} = 240 mA$, Tcase = 25°C



CMPA1D1E025F Power Dissipation De-rating Curve



Note 1. Area exceeds Maximum Case Temperature (See Page 2).

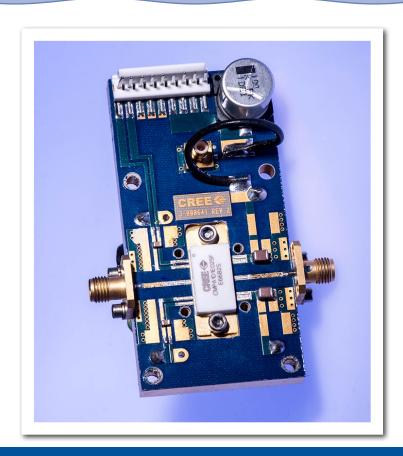
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CMPA1D1E025F-TB Demonstration Amplifier Circuit Bill of Materials

Designator	Description	Qty
C5	CAP ELECT 100UF 80V AFK SMD	1
C1,C2	CAP, 33000PF, 0805,100V, X7R	2
C3,C4	CAP, 2.2UF, 100V, 10%, X7R, 1210	4
J1,J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST, 20MIL	2
]4	CONN, SMB, STRAIGHT JACK RECEPTACLE, SMT, 50 OHM, Au PLATED	1
J3	HEADER RT>PLZ .1CEN LK 9POS	1
W1	WIRE, BLACK, 22 AWG ~ 1.50"	1
W2	WIRE, BLACK, 22 AWG ~ 1.75"	1
W3	WIRE, BLACK, 22 AWG ~ 2.0"	1
	PCB, TEST FIXTURE, TACONICS RF35P, 20 MILS, 440208 PKG	1
	2-56 SOC HD SCREW 1/4 SS	4
-	#2 SPLIT LOCKWASHER SS	4
Q1	CMPA1D1E025F	1

CMPA1D1E025F-TB Demonstration Amplifier Circuit

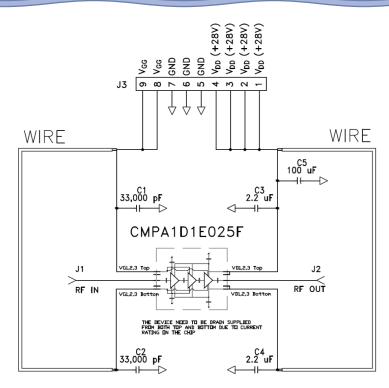


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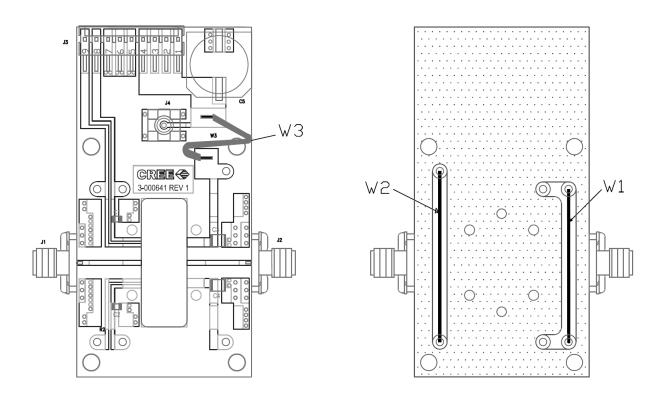
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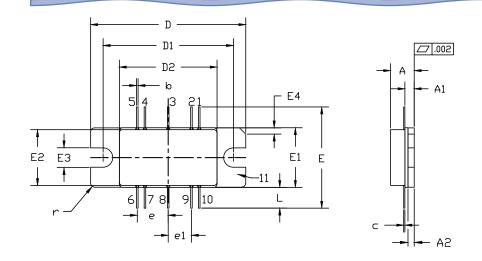
CMPA1D1E025F-TB Demonstration Amplifier Circuit Outline



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Product Dimensions CMPA1D1E025F (Package Type - 440208)



NDTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.

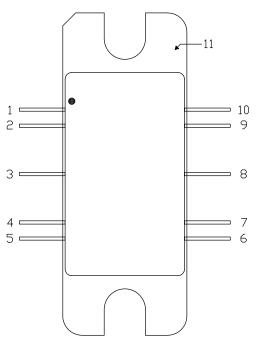
2. CONTROLLING DIMENSION: INCH.

3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM DF 0.020" BEYOND EDGE DF LID.

4. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.

INCHES		MILLIM	IETERS	NOTES
MIN	МАХ	MIN	МАХ	
0.148	0.168	3.76	4.27	
0.055	0.065	1.40	1.65	
0.035	0.045	0.89	1.14	
0.01	TYP	0.254	TYP	10x
0.007	0.009	0.18	0.23	
0.995	1.005	25.27	25.53	
0.835	0.845	21.21	21.46	
0.623	0.637	15.82	16.18	
0.653	TYP	16.59	TYP	
0.380	0.390	9.65	9.91	
0.355	0.365	9.02	9.27	
0.120	0.130	3.05	3.30	
0.035	0.045	0.89	1.14	45° CHAMFER
0.20) TYP	5.08	TYP	4x
0.15) TYP	3.81	TYP	4x
0.115	0.155	2.92	3.94	10x
0.02	5 TYP	.635	TYP	Зx
	MIN 0.148 0.055 0.035 0.01 0.007 0.995 0.835 0.623 0.623 0.653 0.623 0.380 0.355 0.120 0.035 0.200 0.155	MIN MAX 0.148 0.168 0.055 0.065 0.035 0.045 0.007 0.009 0.995 1.005 0.835 0.845 0.623 0.637 0.653 T/P 0.380 0.390 0.355 0.365 0.120 0.130 0.035 0.045 0.200 T/P 0.150 T/P	MIN MAX MIN 0.148 0.168 3.76 0.055 0.065 1.40 0.035 0.045 0.89 0.035 0.045 0.89 0.01 TYP 0.254 0.007 0.009 0.18 0.995 1.005 25.27 0.835 0.845 21.21 0.623 0.637 15.82 0.653 TYP 16.59 0.380 0.390 9.65 0.355 0.365 9.02 0.120 0.130 3.05 0.200 TYP 5.08 0.150 TYP 3.81 0.115 0.155 2.92	MIN MAX MIN MAX 0.148 0.168 3.76 4.27 0.055 0.065 1.40 1.65 0.035 0.045 0.89 1.14 0.01 TYP 0.254 TYP 0.007 0.009 0.18 0.23 0.995 1.005 25.27 25.53 0.835 0.845 21.21 21.46 0.623 0.637 15.82 16.18 0.653 TYP 16.59 TYP 0.380 0.390 9.65 9.91 0.355 0.365 9.02 9.27 0.120 0.130 3.05 3.30 0.035 0.045 0.89 1.14 0.200 TYP 5.08 TYP 0.150 TYP 3.81 TYP

Pin Number	011
Pin Number	Qty
1	Gate Bias
2	NC
3	RF In
4	NC
5	Gate Bias
6	Drain Bias
7	Drain Bias
8	RF Out
9	Drain Bias
10	Drain Bias
11	Source

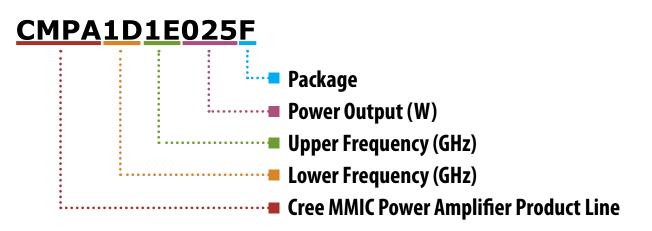


PIN 1: GATE BIAS 6: DRAIN BIAS 2: GATE BIAS 7: DRAIN BIAS 3: RATE N 8: RF DUT 4: GATE BIAS 9: DRAIN BIAS 5: GATE BIAS 10: DRAIN BIAS 11: SDURCE

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Part Number System



Parameter	Value	Units
Lower Frequency	13.5	GHz
Upper Frequency ¹	14.5	GHz
Power Output	25	W
Package	Flange	-

Table 1.

Note¹: Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Character Code	Code Value
А	0
В	1
С	2
D	3
Е	4
F	5
G	6
Н	7
J	8
К	9
Examples:	1A = 10.0 GHz 2H = 27.0 GHz

Table 2.

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